

# Device Modeling Report

COMPONENTS:  
DIODE/ GENERAL PURPOSE RECTIFIER/ STANDARD  
PART NUMBER: 20DL2C48A  
MANUFACTURER: TOSHIBA

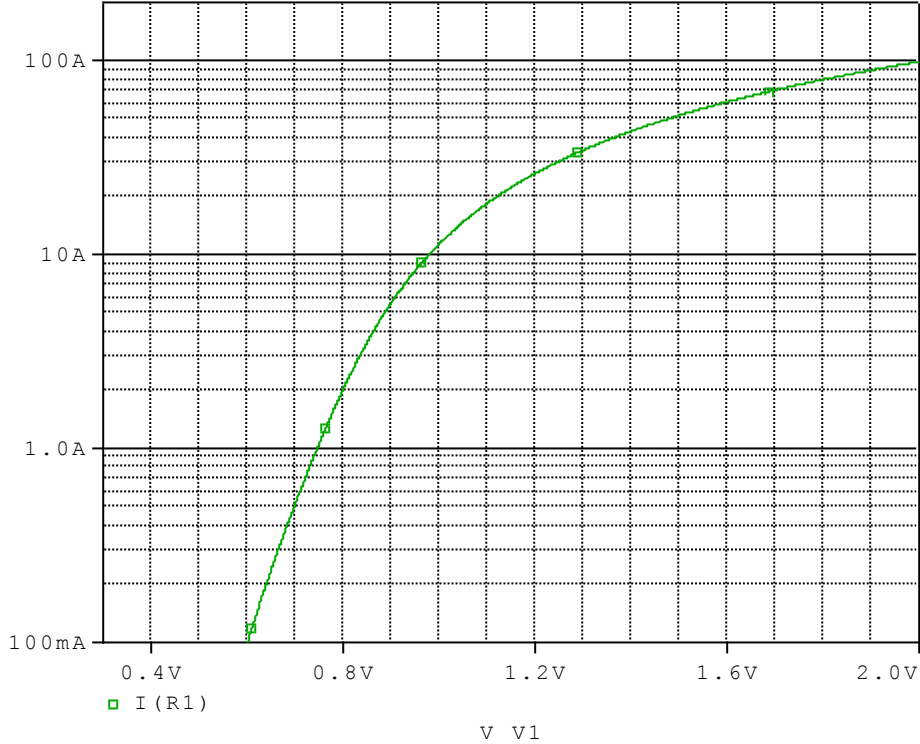


**Bee Technologies Inc.**

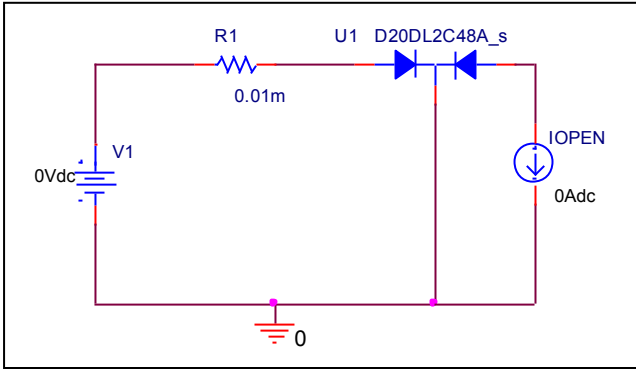
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

# Forward Current Characteristic

## Circuit Simulation Result

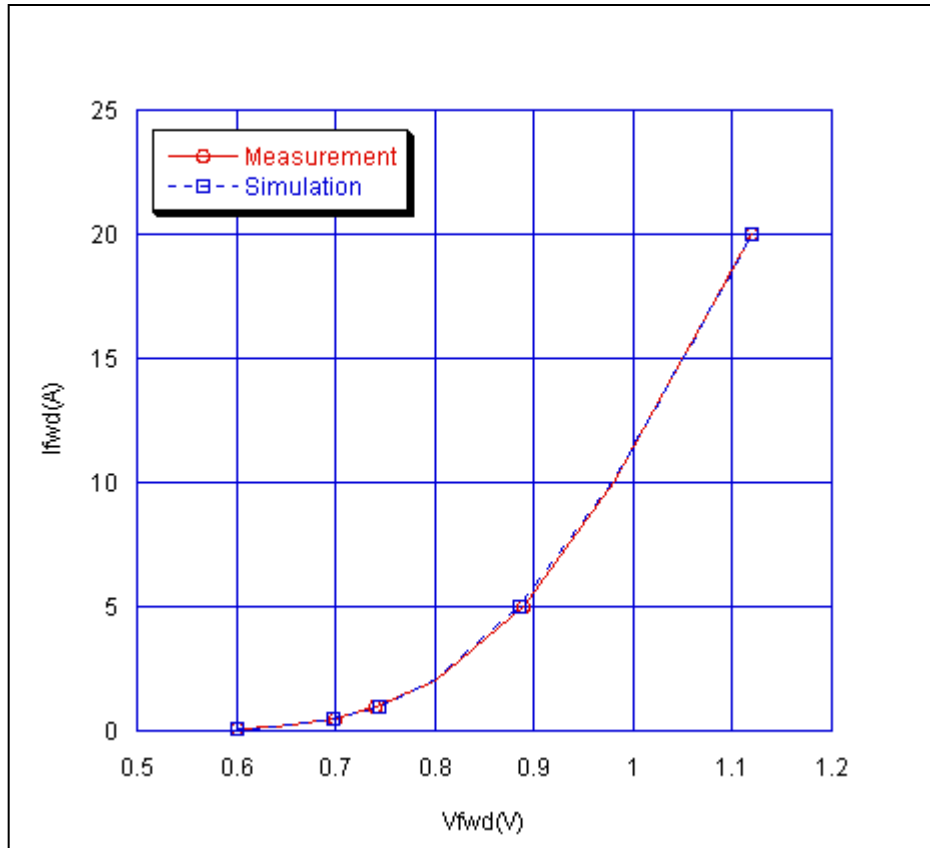


## Evaluation Circuit



## Comparison Graph

### Circuit Simulation Result

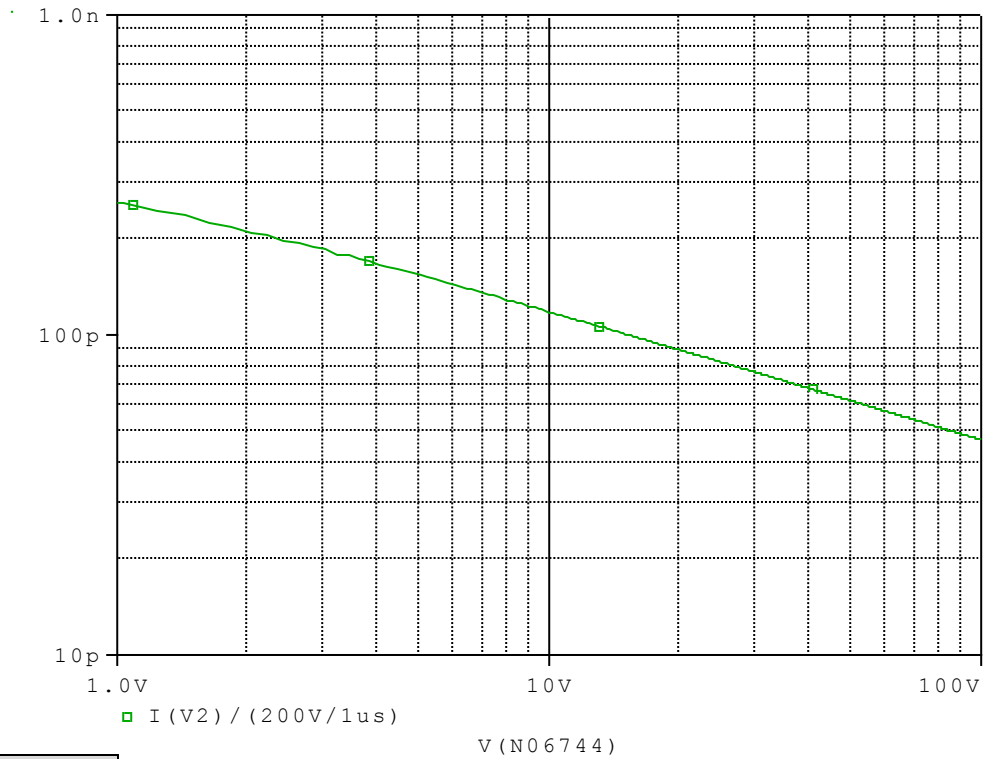


### Simulation Result

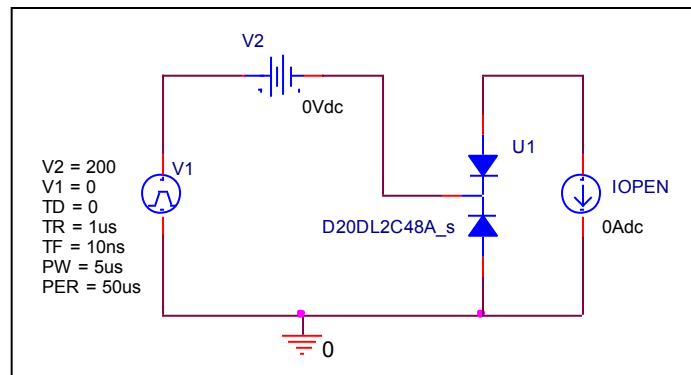
Ifwd(A)	Vfwd(V)		%Error
	Measurement	Simulation	
0.1	0.600	0.601	-0.167
0.2	0.640	0.639	0.156
0.5	0.700	0.698	0.286
1	0.740	0.745	-0.676
2	0.800	0.799	0.125
5	0.890	0.886	0.449
10	0.980	0.979	0.102
20	1.120	1.117	0.268

# Capacitance Characteristic

## Circuit Simulation Result

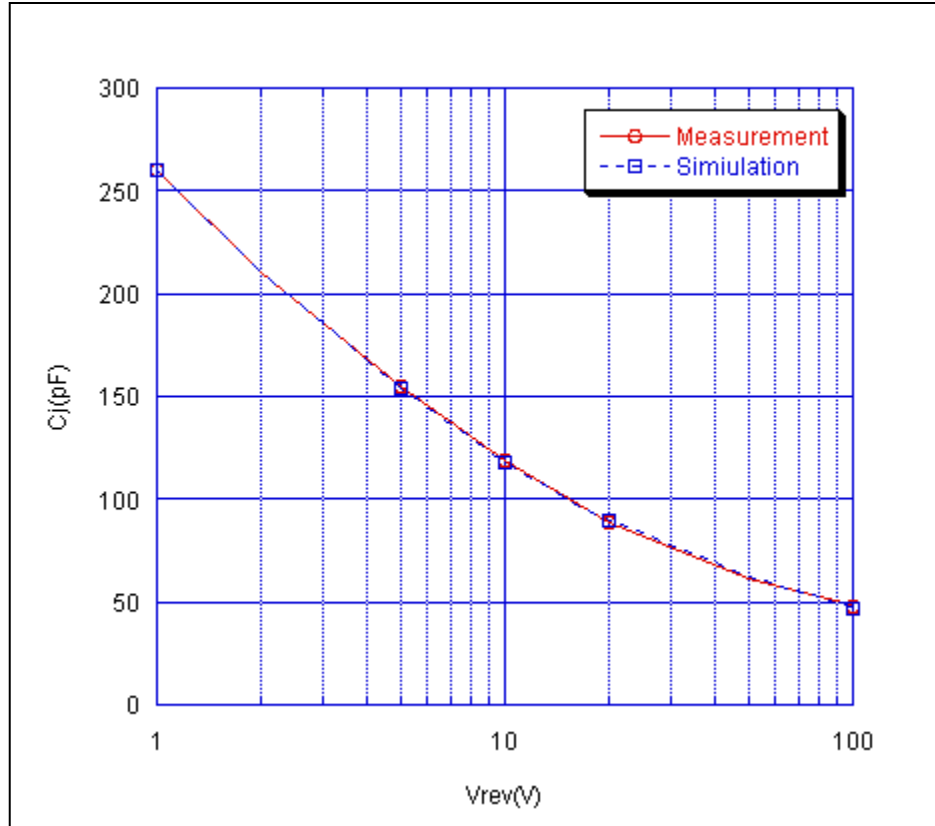


## Evaluation Circuit



# Comparison Graph

## Circuit Simulation Result

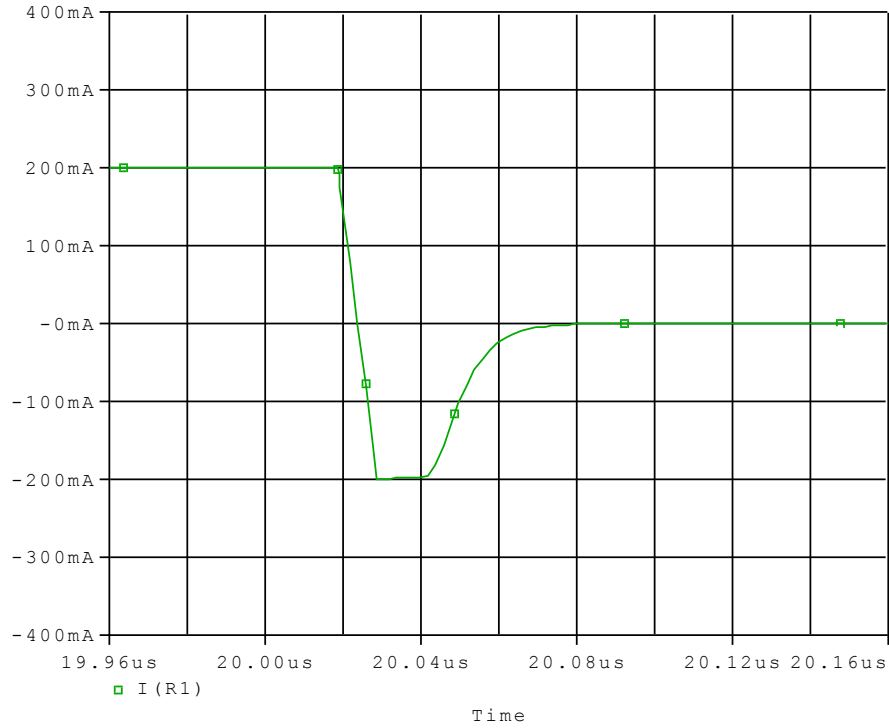


## Simulation Result

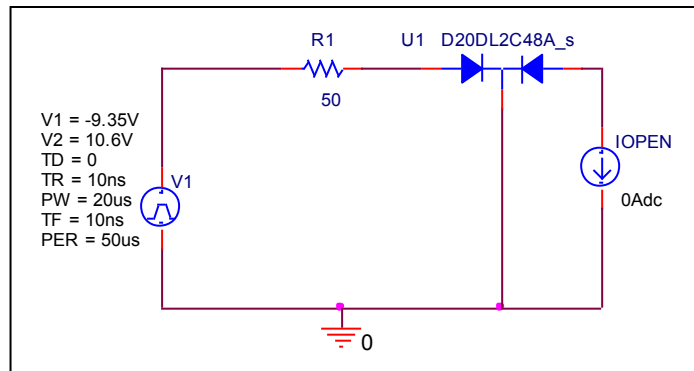
Vrev(V)	Cj(pF)		%Error
	Measurement	Simulation	
1	260.000	260.027	-0.010
2	210.000	210.729	-0.347
5	155.000	153.655	0.868
10	119.000	118.148	0.716
20	89.000	90.000	-1.124
50	61.000	62.271	-2.084
100	48.000	47.000	2.083

# Reverse Recovery Characteristic

## Circuit Simulation Result



## Evaluation Circuit

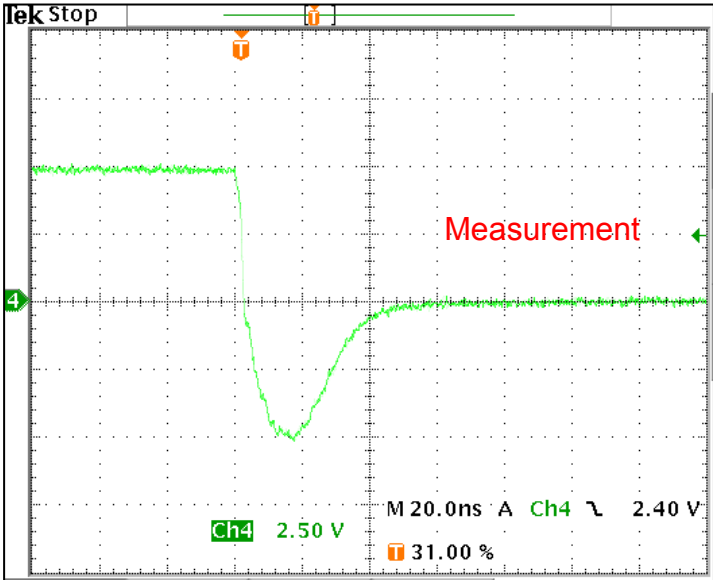


## Compare Measurement vs. Simulation

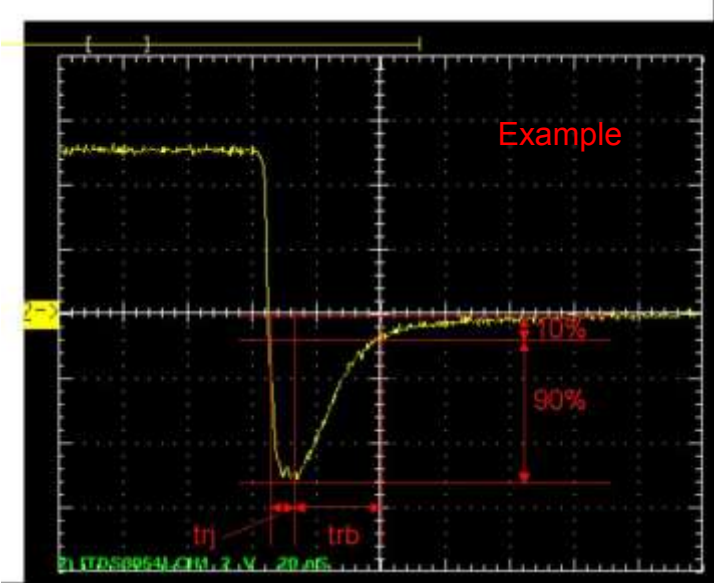
	Measurement		Simulation		%Error
<b>trr</b>	<b>36.800</b>	<b>ns</b>	<b>36.870</b>	<b>ns</b>	<b>0.190</b>

# Reverse Recovery Characteristic

# Reference



$T_{rj} = 14.8(\text{ns})$   
 $T_{rb} = 22(\text{ns})$   
Conditions:  $I_{fwd} = I_{rev} = 0.2(\text{A})$ ,  $R_I = 50$



Relation between  $t_{rj}$  and  $t_{rb}$